

Low-Frequency General-Purpose Amplifier Applications

Applications

· AF power amplifier, medium-speed switching, smallsized motor drivers.

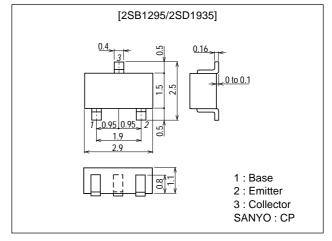
Features

- · Large current capacity.
- · Low collector to emitter saturation voltage.
- · Ultrasmall-sized package permitting sets to be made smaller and slimer.

Package Dimensions

unit:mm

2018B



(): 2SB1295

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)15	V
Collector-to-Emitter Voltage	V _{CEO}		(–)15	V
Emitter-to-Base Voltage	V _{EBO}		(-)5	V
Collector Current	IC		(–)0.8	Α
Collector Current (Pulse)	I _{CP}		(–)3	Α
Collector Dissipation	PC		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V _{CB} =(-)12V, I _E =0			(-)100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)100	nA
DC Current Gain	h _{FE} 1	V _{CE} =(-)2V, I _C =(-)50mA	135*		900*	
					(600)	
	h _{FE} 2	V _{CE} =(-)2V, I _C =(-)800mA	80			

^{*:} The 2SB1295/2SD1935 are classified by 50mA h_{FE} as follows:

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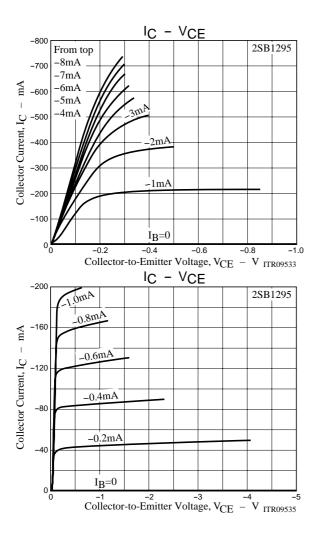
2SB1295	Rank	5	6	7	2SB1935	Rank	5	6	7	8
	hÆ	135 to 270	200 to 400	300 to 600		h _{FE}	135 to 270	200 to 400	300 to 600	450 to 900

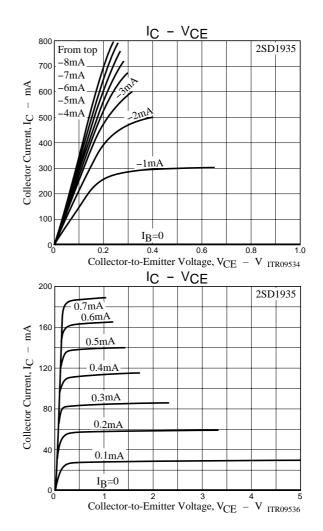
 $Marking \colon 2SB1295 : UL/2SD1935 : CT \\ h_{FE} \; rank \colon 2SB1295 : 5, \, 6, \, 7/2SD1935 : 5, \, 6, \, 7, \, 8$

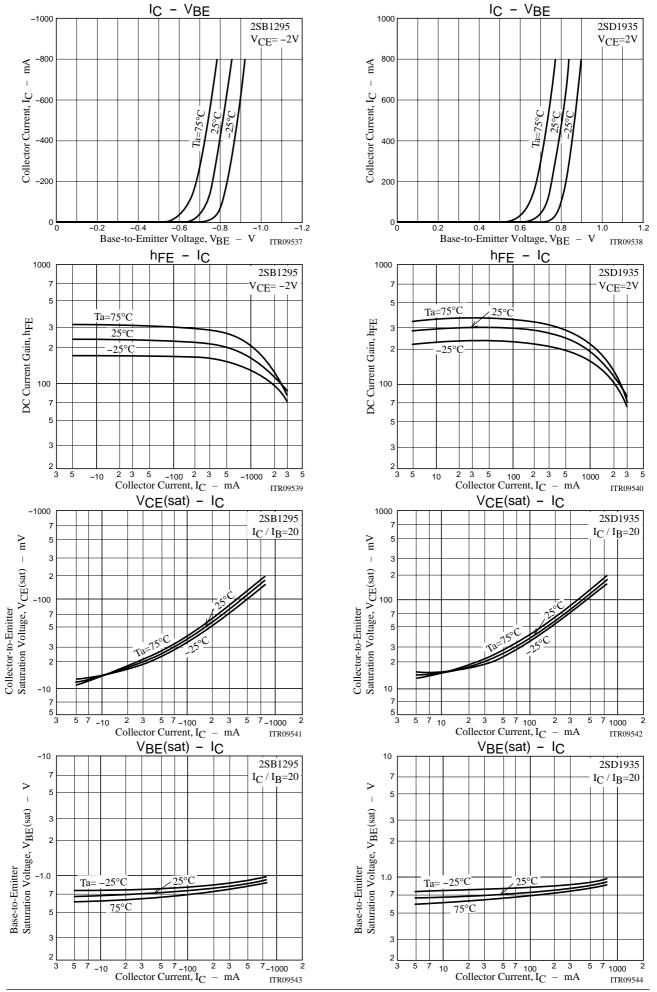
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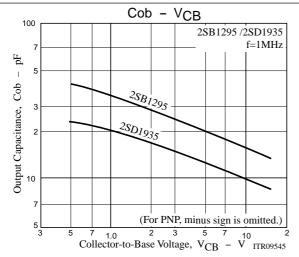
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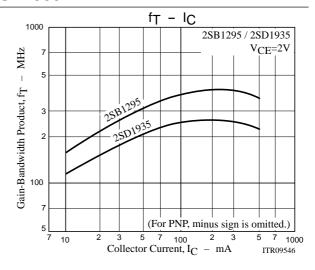
Parameter	Symbol	Conditions		Unit		
Farameter		Conditions		typ	max	Offic
Gain-Bandwidth Product	fΤ	V _{CE} =(-)2V, I _C =(-)50mA		200		MHz
Gain-Bandwidtii FTOUUCt				(300)		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(15)		pF
Output Capacitance				10		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)} 1	I _C =(-)5mA, I _B =(-)0.5mA		(–)10	(-)25	mV
Collector-to-Emitter Saturation Voltage	V _{CE(sat)} 2	I _C =(-)400mA, I _B =(-)20mA		(-)100	(-)200	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)400mA, I _B =(-)20mA		(-)0.9	(-)1.2	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	$I_{C}=(-)10\mu A, I_{E}=0$	(–)15			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =(−)1mA, R _{BE} =∞	(–)15			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =(–)10μA, I _C =0	(–)5			V

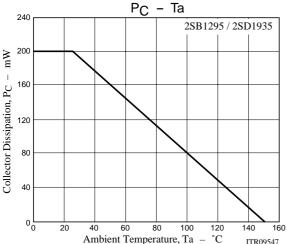












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